



#### AH1711Q/AH1712Q/AH1713Q/AH1714Q

# LOW-VOLTAGE, HIGH-SENSITIVITY AUTOMOTIVE HALL EFFECT LATCH SWITCH

#### **Description**

The AH1711Q/AH1712Q/AH1713Q/AH1714Q is an AEC-Q100 qualified low-voltage, high-sensitivity Hall effect latch IC designed for brushless DC-motor commutation speed measurement, angular or linear encoders and position sensors in automotive applications. To support a wide range of demanding applications, the design is optimized to operate at 2.4V to 5.5V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the device provides a reliable solution over the whole operating range.

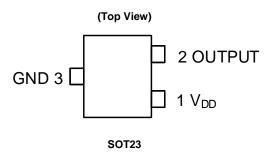
The open-drain output of AH1711Q/AH1712Q/AH1713Q can be switched on when applying South pole with sufficient magnetic near the top of the package, while North pole with sufficient magnetic strength causes the open-drain output switched off (AH1714Q polarity inverted). When the magnetic flux density (B) perpendicular to the package is larger than the operate point (Bop) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point (Brp).

#### **Features**

- Latch Operation
- High Sensitivity: Bop and Brp of ±7 Gauss and ±18 Gauss
- Open-Drain Output
- 2.4V to 5.5V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Fast 30kHz Sensing Bandwidth
- -40°C to +150°C Operating Temperature
- ESD: HBM 8kV, CDM 2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SOT23 Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green Device (Note 3)
- The AH1711Q/AH1712Q/AH1713Q/AH1714Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Pin Assignments**



#### **Applications**

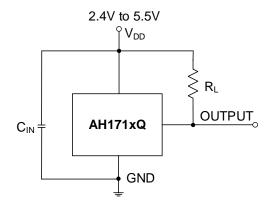
- Brushless DC-motor commutation
- Revolution per minute (RPM) measurements
- Wheel speed/angular/speed sensing
- Fuel pumps/windows/sunroofs/sliding doors
- Human machine interface knobs

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit** (Note 4)



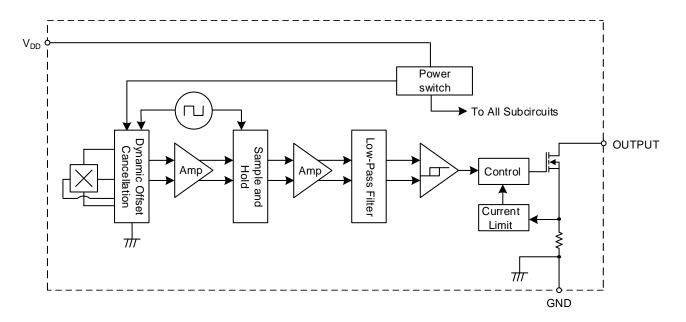
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R<sub>L</sub> is the pullup resistor.

### **Pin Descriptions**

Package: SOT23

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	OUTPUT	Output
3	GND	Ground

# **Functional Block Diagram**





### Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic	Value	Unit	
V <sub>DD</sub>	Supply Voltage (Note 6)		-0.3 to 6.0	V
Vout_max	Output Off Voltage (Note 6)		6.0	V
Іоит	Output Current		60	mA
В	Magnetic Flux Density	Unlimited		
PD	Package Power Dissipation	SOT23	230	mW
Ts	Storage Temperature Range	-65 to +150	°C	
TJ	Maximum Junction Temperature	+170	°C	
ESD HBM	Electros Static Discharge Withstand - Human Body Model (HB	8	kV	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model (	CDM)	2	kV

Notes:

- 5. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.
- 6. The absolute maximum V<sub>DD</sub> of 6V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

#### Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V <sub>DD</sub>	Supply Voltage	2.4 to 5.5	V
Іоит	Output Sinking Current	0 to 20	mA
TA	Operating Temperature Range	-40 to +150	°C

#### Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +150°C, VDD = 2.4V to 5.5V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OUT</sub> = 20mA	_	0.2	0.4	V
ILKG	Output Leakage Current (When Output is Off)	Vout = 5.5V, output off		< 0.1	3	μA
l	Supply Current	Output open, T <sub>A</sub> = +25°C		2.0	2.8	mA
I <sub>DD</sub>	Зарріу Сапені	Output open, T <sub>A</sub> = -40°C to +150°C	_	_	3.2	mA
tp_on	Device Power-On Time (Startup Time)	V <sub>DD</sub> ≥ 2.4V, B < BRP (min) – 10G B > BOP (max) + 10G (Note 7) dV <sub>DD</sub> /dt > 2V/µs	_	38	70	μs
POS	Power-On State, Output	Power-on time < tP_ON, B = 0		Low		_
fc	Chopping Frequency	V <sub>DD</sub> ≥ 2.4V	_	800	_	kHz
t <sub>d</sub>	Response Time Delay (Time from Magnetic Threshold Reached to the Start of the Output Rise or Fall)	(Note 9)	_	10	20	μs
t <sub>r</sub>	Output Rising Time (External Pullup Resistor R <sub>L</sub> and Load Capacitance Dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.2	1	μs
t <sub>f</sub>	Output Falling Time (Internal Switch Resistance and Load Capacitance Dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.1	1	μs
f <sub>BW</sub>	Sensing Bandwidth	B ≥ ±400G and square wave magnetic field (Note 9)	20	30	_	kHz
locL	Output Current Limit	B > B <sub>OP</sub> (Note 10)	30	_	60	mA

Notes:

<sup>7.</sup> When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (2.4V to 5.5V) to guarantee the output sampling. The output state is valid after the startup time of 38µs typical from the operating voltage reaching 2.4V.

<sup>8.</sup> Typical values are defined at T<sub>A</sub> = +25°C. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

<sup>9.</sup> Guaranteed by design, process control and characterization. Not tested in production.

<sup>10.</sup> The device will limit the output current to current limit of I<sub>OCL</sub>.

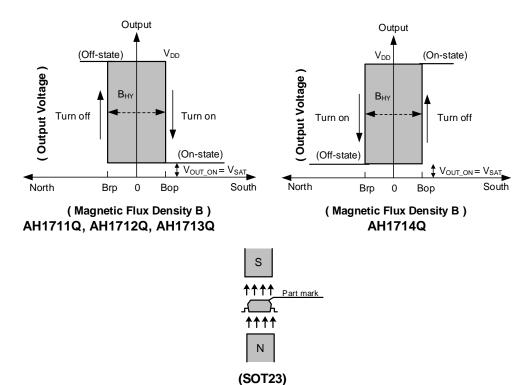


#### Magnetic Characteristics (Notes 11 & 12) (T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 2.4V to 5.5V, unless otherwise specified.)

Part Name	Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Output Polarity	
	Вор	Operation Reint	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-2	7	20			
	Вор	Operation Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-5	7	29			
AH1711Q	Dun	Release Point	T <sub>A</sub> = -40°C to +125°C	-20	-7	2	Gauss	Direct	
AHITTIQ	Brp	Release Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-29	-7	5	Gauss	Direct	
	D	Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	3.5	14	_			
	B <sub>HY</sub>	Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	3	14	_			
	Вор	Operation Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	5	18	37			
	Бор	Operation Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	2	18	45			
Λ∐1712 <b>∩</b>	AH1712Q Brp BHY	Release Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-37	-18	-5	Gauss	Direct	
AIII/12Q		Kelease Fullit	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-45	-18	-2	Gauss		
		Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	23	36	_			
			$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	17.5	36	_			
	Bop AH1713Q Brp	Operation Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	16	50	81		Direct	
		Operation Fount	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	15	50	88			
AH1713Q		Release Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-81	-50	-16	Gauss		
AIII713Q	ыр	ivelease i oliit	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-88	-50	-15	Jauss	Direct	
	Вну	Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	60	100	_			
	DHY	Thysieresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	50	100	_			
	Вор	Operation Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	5	18	37			
	Бор	Operation Foint	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	2	18	45			
AH1714Q	Drn	Release Point	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-37	-18	-5	Gauss	Inverted	
AH1714Q	Brp	Release Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-45	-18	-2	Gauss	inverted	
	D. n.	Hysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	23	36	_			
	Вну	Trysteresis (Note 13)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	17.5	36				

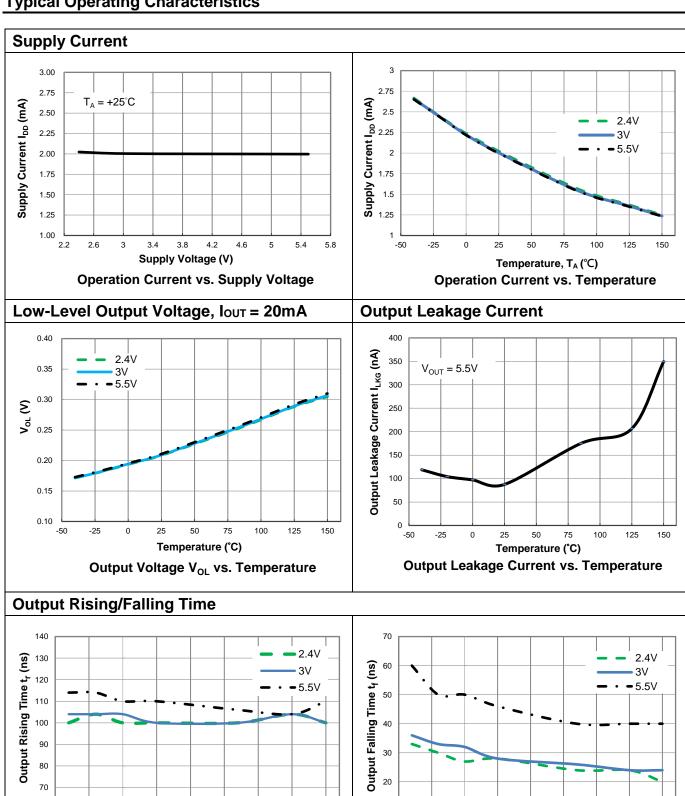
Notes:

- 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (2.4V to 5.5V) to guarantee the output sampling. The output state is valid after the startup time of 38µs typical from the operating voltage reaching 2.4V.
- 12. Typical values are defined at T<sub>A</sub> = +25°C. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.





## **Typical Operating Characteristics**



0

25

50

Temperature (°C)

Output Rising Time (t<sub>r</sub>) vs. Temperature

75

100

125

150

60

-50

-25

10

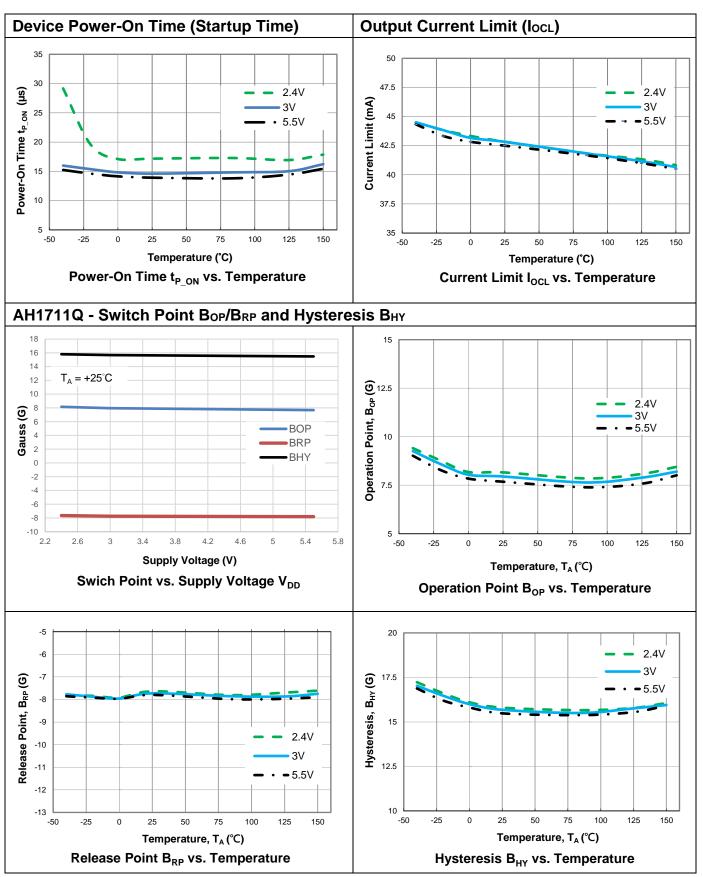
-50

Temperature (°C)

Output Falling Time (t<sub>f</sub>) vs. Temperature

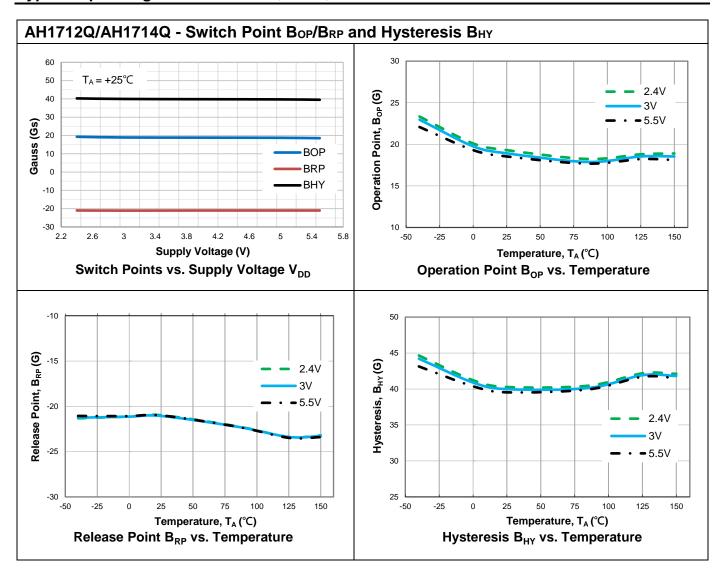


### **Typical Operating Characteristics** (continued)



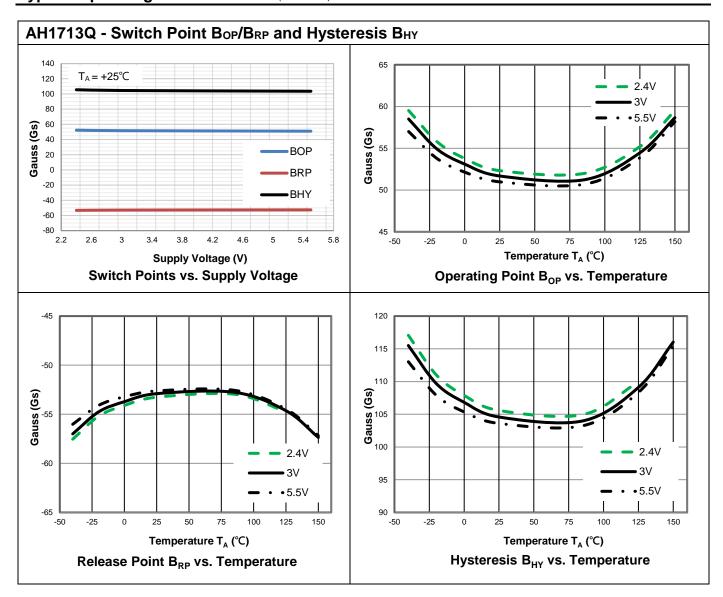


### **Typical Operating Characteristics** (continued)





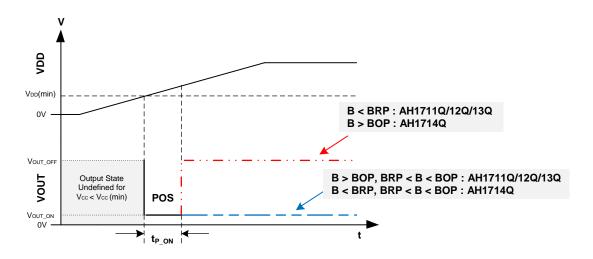
# **Typical Operating Characteristics** (continued)





# **Application Information**

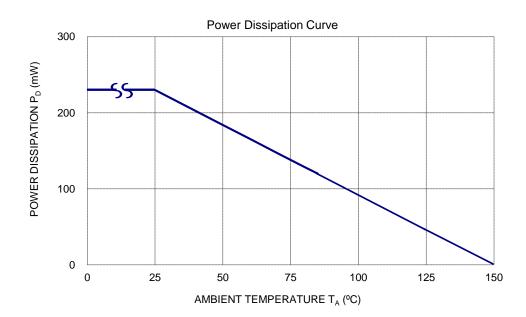
Power-On State (POS)



#### **Thermal Performance Characteristics**

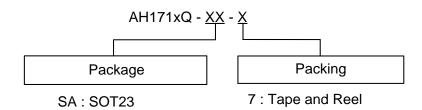
Package: SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0





# **Ordering Information**



Part Number	Part Number Suffix	Package Code	Pookogo	Packing		
Part Number	Fait Number Sumx	Package Code	Package	Qty.	Carrier	
AH1711Q-SA-7	-7	SA	SOT23	3,000	7" Tape and Reel	
AH1712Q-SA-7	-7	SA	SOT23	3,000	7" Tape and Reel	
AH1713Q-SA-7	-7	SA	SOT23	3,000	7" Tape and Reel	
AH1714Q-SA-7	-7	SA	SOT23	3,000	7" Tape and Reel	

### **Marking Information**

Package Type: SOT23



 $\underline{XXX}$  $\underline{Y} \underline{W} \underline{X}$ 

XXX: Identification Code  $\underline{Y}$ : Year 0 to 9 (ex: 3 = 2023) <u>W</u>: Week: A to Z: week 1 to 26; a to z: week 27 to 52; z represents week 52 and 53

X: Internal Code

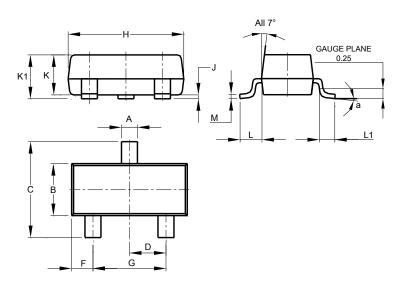
Part Number	Package	Identification Code
AH1711Q-SA-7	SOT23	XKQ
AH1712Q-SA-7	SOT23	XMQ
AH1713Q-SA-7	SOT23	XNQ
AH1714Q-SA-7	SOT23	XPQ



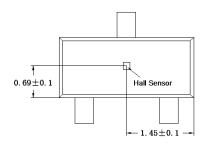
# **Package Outline Dimensions**

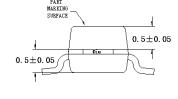
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	Dimens	ions in	mm				





TOP VIEW

Side VIEW

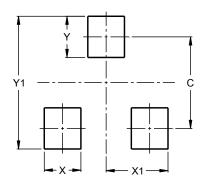
**Sensor Location** 



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

#### **Mechanical Data**

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.009 grams (Approximate)



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